

Metallization And Metal-semiconductor Interfaces

by NATO Advanced Research Workshop on Metallization and Metal-Semiconductor Interfaces (; Inder P Batra; North Atlantic Treaty Organization

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978-0-444-81889-8 Elsevier Schottky metal particles, the result of a unique metal semiconductor interface that results when the metal . metallization layer-semiconductor interface is a. Introduction to Metallization and Metal - Semiconductor Interfaces .